REVERSE VOLTAGE 50 TO 1000V FORWARD CURRENT 1.0A **RECTIFIER DIODES**

DESCRIPTION

The HFM101~ HFM108 are available in SMA ● package.

ORDERING INFORMATION

Package Type	Part Number				
SMA	HFM101				
	HFM102				
	HFM103				
	HFM104				
	HFM105				
	HFM106				
	HFM107				
	HFM108				
Note	5,000pcs/Reel				
AiT provides all RoHS Compliant Products					

PIN DESCRIPTION



FEATURES

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- Ideally suited for use in very high frequency switching
- power supplies, inverters and as free wheeling diodes
- Ultrafast recovery time for high efficiency
- Excellent high temperature switching
- Soft recovery characteristics
- Cavity-free glass passivated junction
- High temperature soldering guaranteed:
- 260°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension
- Available in SMA package

MECHANICAL DATA

Case: JEDEC DO-214AC,

molded plastic over glass die

Terminals: Plated axial leads, solderable per

MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any Weight: 0.0026oz., 0.075g Handling Precautin: None

REVERSE VOLTAGE 50 TO 1000V FORWARD CURRENT 1.0A SURFACE MOUNT GLASS PASSIVATED HIGH EFFICIENCY RECTIFIER DIODES

ELECTRICAL CHARACTERISTICS

At 25°C ambient temperature unless otherwise specified.

Maximum Ratings & Thermal Characteristics Ratings										
Parameter Symbol	symbol	HFM 101	HFM 102	HFM 103	HFM 104	HFM 105	HFM 106	HFM 107	HFM 108	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	300	400	600	800	1000	٧
Maximum RMS voltage	V_{RMS}	35	70	140	210	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	300	400	600	800	1000	٧
Maximum average forward rectified current 0.375" (9.5mm) lead length at T _A = 75°C	I _{F(AV)}	1.0							Α	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	30								Α
Maximum full load reverse current, full cycle average,0.375"(9.5mm) lead lengths at T _A = 55°C	I _{R(AV)}	100							μА	
Typical thermal resistance	R _{θJA}	50							°C/W	
Operating junction and storage temperature range	TJ, TSTG	-50 to +150						°C		

At 25°C ambient temperature unless otherwise specified.

Electrical Characteristics Ratings										
Parameter Symbol	symbol	HFM 101	HFM 102	HFM 103	HFM 104	HFM 105	HFM 106	HFM 107	HFM 108	Unit
Maximum instantaneous forward voltage at 1.0A	VF		1.00		1.	30		1.85		>
Maximum DC reverse current T _A = 25°C	5.0						μΑ			
at rated DC blocking voltage T _A = 125°C	ik	100								
Typical reverse recovery time NOTE 1	t _{rr}	50 75					ns			
Typical junction capacitance at 4.0V, 1MHz	C₁	17					PF			

NOTE1: $I_F = 0.5A$, $I_R = 1.0A$, $I_{RR} = 0.25A$

NOTE2: Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

SURFACE MOUNT GLASS PASSIVATED HIGH EFFICIENCY RECTIFIER DIODES

TYPICAL CHARACTERISTICS

T_A = 25°C unless otherwise specified. Fig. 1 Forward Current Derating Curve

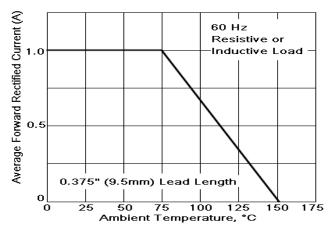


Fig 3. Typical Instantaneous Forward Characteristics

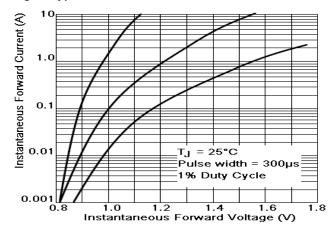


Fig 5. typical transient thermal impedance

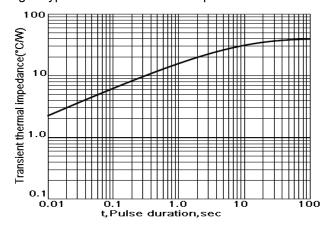


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

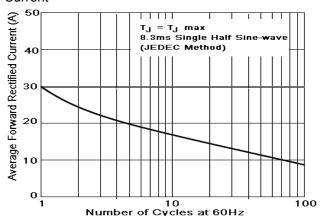


Fig 4. Typical Reverse Characteristics

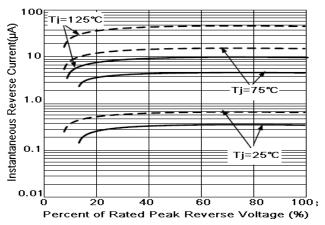
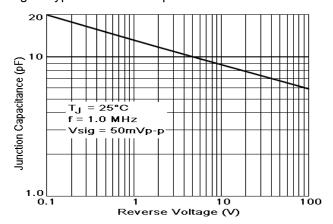
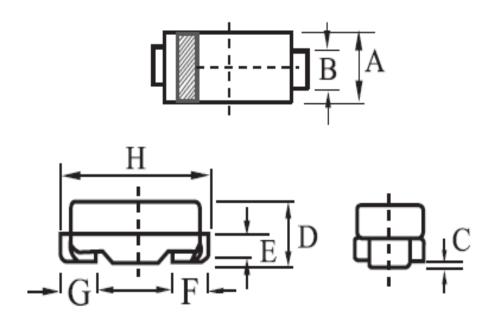


Fig 6. Typical Junction Capacitance



PACKAGE INFORMATION

Dimension in SMA Package (Unit: mm)



DIM	INC	HES	MILLIMETERS				
DIM	MIN	MAX	MIN	MAX			
А	0.086	0.110	2.20	2.80			
В	0.051	0.067	1.30	1.70			
С	-	0.008	-	0.20			
D	0.067	0.100	1.70	2.55			
Е	0.008	0.051	0.20	1.30			
F	0.035	0.059	0.90	1.50			
G	0.185	0.209	4.70	5.30			
Н	0.035	0.059	0.90	1.50			



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